

PROGRAM

TUESDAY, 25TH FEBRUARY

REGISTRATION 13:00 – 17:00		
	ROOM	EDS MINI – COLLOQUIUM
8:30 – 9:10	AQCUA 3	“Leveraging semiconductor technology for the benefit of society” Fernando Guarín, PhD GlobalFoundries, East Fishkill, NY, USA
9:10 – 10:00	AQCUA 3	“Semiconductor Industry: A story of unprecedented growth, and we are just getting started!” Ravi Todi, PhD Western Digital, Milpitas, CA, USA
10:00 – 10:30	Coffee Break	
10:30 – 11:20	AQCUA 3	“Nanoelectronics to Nanotechnology: Challenges and Direction” Durga Misra, PhD New Jersey Institute of Technology, NJIT, NJ USA
11:20 – 12:00	AQCUA 3	“Reliability and Instability of GaN Power Field-Effect Transistors” Jesús del Álamo, PhD Massachusetts Institute of Technology, Cambridge, MA, USA
12:00 – 13:10	AQCUA 3	“Current Progress and Advances in Polymer Solar Cells” Lluís F. Marsal, PhD University Rovira i Virgili Tarragona, Spain
13:10 – 14:20	LUNCH / SRC MEETING	
13:00 – 17:00	EDS – ETC SNAP CIRCUITS TRAINING [TEC SJO]	
14:20 – 14:50	AQCUA 3	“Influence of Substrate Bias on the Mobility of Nanowire MOSFETs” Marcelo Antonio Pavanello Department of Electrical Engineering, Centro Universitario FEI, Sao Bernardo do Campo, Brazil

MOS – AK		
14:50 – 15:20	AQUA 3	<p>“Analytical Current-Voltage Model for Double Gate a-IGZO TFTs with Symmetric Structure” Antonio Cerdeira Altuzarra Solid-State Electronic Section, Dept. Electrical Engineering CINVESTAV, Mexico City</p>
15:20 – 15:50	AQUA 3	<p>“Approaches for Analytical (Compact) Modeling of Tunneling Currents in MOS Transistors” Alexander Kloes Technische Hochschule Mittelhessen – University of Applied Sciences NanoP – Competence Center for Nanotechnology and Photonics Giessen, Germany</p>
15:20 – 16:20	Coffee Break	
16:20 – 16:50	AQUA 3	<p>“Modeling the Junctionless Ion Sensitive Field Effect Transistor” Jean-Michel Sallese Swiss Federal Institute of Technology Lausanne (EPFL), 1015 Lausanne, Switzerland</p>
16:50 - 17:20	AQUA 3	<p>“The area scaling of charge trap induced time-dependent variability” Gilson Wirth, UFRGS, Porto Alegre, Brazil</p>
17:20 - 17:50	AQUA 3	<p>“Characterization and modeling of 1/f noise in organic and IGZO TFTs” Benjamin Iñiguez, Department of Electrical, Electronics Engineering and Automachine, Universitat Rovira i Virgili, 43007 Tarragona, Spain</p>
18:00 – 19:00	AQUA 3	SRC MEETING (private)
19:00 – 21:00	WELCOME COCKTAIL	

WEDNESDAY, 26TH FEBRUARY

REGISTRATION 7:00 – 17:00		
	OPENING CEREMONY	
8:00 – 8:30	VENTO 3	VENTO 2
8:30 – 9:00	Invited “Status, Trends, Challenges and Possible Solutions for Nanoelectronic Devices” Francis Balestra	LASCAS – Imaging Techniques
9:00 – 9:20	A-2	
9:20 – 9:40	A-3	
9:40 – 10:00	A-4	
10:00 – 10:30	Coffee Break	
10:30 – 11:30	Keynote: “Integrated Platform Research” Dr. Vida Ilderem Director of Integrated Platform Research, VP Intel Labs.	
11:30 – 13:00	LUNCH	
13:00 – 14:00	Keynote: “Cognitive and Computational Neuroscience” Dr. Shihab Shamma University of Maryland UMD	
14:00 – 15:00	Keynote: “Nanoscale III-V Electronics: InGaAs FinFETs and Vertical Nanowire MOSFETs” Jesus A. del Alamo Massachusetts Institute of Technology MIT	
15:00 – 16:00	Posters/LAEDC Flash Session*	Coffee Break
16:20 – 16:50	Invited “Status and Future Prospects of CMOS Scaling and Moore's Law – A Personal Perspective” Frank Schwierz	LASCAS - Sensors
16:50 – 17:20	Invited “A Journey from Devices to Systems with Negative Capacitance Transistors (NCFETs)” Hussam Amrouch	LASCAS - Sensors

17:20 – 17:40	D-3	M-1
17:40 – 18:00	D-4	M-2
18:00 – 18:20	D-5	M-3
18:20 – 18:40	D-6	M-4
18:40 – 19:00		M-5
19:00 – 21:00	IEEE YP/WIE NETWORKING SESSION	

Device Physics

A-1	Invited “Status, Trends, Challenges and Possible Solutions for Nanoelectronic Devices” Francis Balestra
A-2	Time Dependent Threshold Voltage Variability due to Random Telegraph Noise Gilson Wirth
A-3	Microwave High-Voltage CBiJFET Technology for Analog Integrated Circuits Dmitry Drozdov, Nikolay Prokopenko, Evgeny Savchenko, Pavel Dukanov, Andrey Grushin and Anna Bugakova
A-4	MiSiM: Microstructured Fibers' Simulator Paola Montero, Ricardo Román-Brenes, Francisco Siles and Jaime Cascante-Vindas

Devices and Materials

D-1	Invited “Status and Future Prospects of CMOS Scaling and Moore's Law – A Personal Perspective” Frank Schwierz
D-2	Invited “A Journey from Devices to Systems with Negative Capacitance Transistors (NCFETs)” Hussam Amrouch
D-3	Analysis of the Electrical Parameters in SOI n-type Junctionless Nanowire Transistors at High Temperatures Thales Augusto Ribeiro and Marcelo Antonio Pavanello
D-4	Analysis of the Thermal Properties of Self-Cascade Structures Composed by UTBB Transistors Fernando José Costa, Renan Trevisoli Doria, Michelly De Souza and Rodrigo Trevisoli Doria
D-5	Dynamic Response Considerations in Typical CMOS-MEMS Accelerometer Structures Benito Granados-Rojas, Alfredo Reyes-Barranca, Griselda Stephany Abarca-Jiménez and Yesenia Eleonor Gonzalez-Navarro

D-6	Single and complex devices on three topological configurations of HfO₂ based RRAM Óscar G. Ossorio, Samuel Poblador, Guillermo Vinuesa, Salvador Dueñas, Helena Castán, Marcos Maestro-Izquierdo, Mireia G. Bargalló and Francesca Campabadal
D-7	Stress- and Trap-Induced Body Fluctuations in 45nm SOI MOSFETs Edmundo Gutierrez, Oscar Huerta and Omar Lopez

Modeling

M-1	Equation-based modeling of electrothermal behavior of a SiC MOSFET chip during a short circuit Yannick Dumollard, Emmanuel Batista, Jean-Marc Dienot and Laurent Pecastaing
M-2	Dynamic Validation of the Full Model for AOSTFTs using a Ring Oscillator based on a-IGZO TFTs Jorge Gaspar, Yoanlys Hernandez, Magali Estrada, Antonio Cerdeira and Benjamin Iñiguez
M-3	Modernization of Low-Temperature JFET Models Built into LTspice CAD Systems, Taking into Account the Results of their Experimental Study Oleg Dvornikov, Valentine Dziatlau, Vladimir Tchekhovski, Nikolay Prokopenko, Alexey Zhuk and Anna Bugakova
M-4	Parameter extraction and compact drain current model for IGZO transistor from 210K up to 370K Harold Cortes-Ordonez, Wondwosen Eshetu Muhea, Magali Estrada, Antonio Cerdeira, Gerard Ghibaudo, Xavier Mescot and Benjamin Iñiguez Nicolau
M-5	Invited: Schottky barrier height extraction of multi-channel one-dimensional FETs, Anibal Pacheco-Sanchez, Eloy Ramirez-Garcia, Mauro Alberto Enciso-Aguilar and David Jiménez

THURSDAY, 27TH FEBRUARY

	VENTO 3	VENTO 2
8:20 – 8:50	Invited “Exploring Quantum Tunneling in Ultrathin Transistors with Multiple Top Gates” Stefan Blawid	LASCAS – Artificial Intelligence
8:50 – 9:20	Invited “Self-Heating in FinFETs: Characterization, Reliability and Impact on Logic Circuits” Durga Misra	
9:20 – 9:40	D-10	
9:40 – 10:00	D-11	
10:00 – 10:30	Coffee Break	
10:30 – 11:30	Keynote: “Overview of 5G Radio Systems, Requirements, Challenges, and Research Areas” Dr. Sayfe Kiaei Arizona State University ASU	
11:30 – 13:00	LUNCH	
13:00 – 13:50	Keynote: “Energy-Scalable Many-Core Servers: Follow Your Brain!” Dr. David Atienza École Polytechnique Fédérale de Lausanne EPFL	
13:50 – 14:20	Invited “Granularity Effects in Electromigration” Lado Filipovic	Invited “Threshold Voltage Adjustment in Organic Thin-film Transistors Through the Use of Interface Amino Acids Interlayers” Eloi Ros
14:20 – 14:40	Invited “Electrical Characterization of Advanced MOSFETs Towards Analog and RF Applications” Valeriya Kilchytska	O-2
14:40 – 14:50		O3
14:50 – 15:00	Invited “Emerging CMOS Compatible Magnetic Memories and Logic” Viktor Sverdllov	O4
15:00 – 15:10		
15:10 – 15:20		
15:20 – 15:50	Coffee Break	

15:50 – 16:10	A-6	Invited “Threshold Voltage of Organic Field-effect Transistors” Yvan Bonnasieux
16:10 – 16:20	M-6	
16:20 – 16:30		O-6
16:30 – 16:40	M-7	O-7
16:40 – 16:50		O-8
16:50 – 17:00	M-8	
17:00 – 17:10		
17:10 – 17:20	M-9	
17:20 – 17:30		
17:30 – 21:00	GALA DINNER	

Devices and Materials

D-8	Invited “Exploring Quantum Tunneling in Ultrathin Transistors with Multiple Top Gates” Stefan Blawid
D-9	Invited “Self-Heating in FinFETs: Characterization, Reliability and Impact on Logic Circuits” Durga Misra
D-10	Electrical and Thermal Characterization for SOI p-type FinFET down to Sub- Kelvin Temperatures Omar Lopez Lopez, Ismael Martínez Ramos, Edmundo A. Gutierrez Dominguez, Daniel Durini Romero, Daniel Ferrusca Rodriguez, Miguel Velazquez, Francisco J. De la Hidalga Wade and Victor H. Gómez Rivera
D-11	Technologies for Realisation of Ultra-thin Chips Yogeenth Kumaresan, Nivasan Yogeswaran and Ravinder Dahiya
D-12	Invited “Granularity Effects in Electromigration” Lado Filipovic
D-13	Invited “Electrical Characterization of Advanced MOSFETs Towards Analog and RF Applications” Valeriya Kilchytska
D-14	Invited “Emerging CMOS Compatible Magnetic Memories and Logic” Viktor Sverdlov

Organic Devices

O-1	Invited “Threshold Voltage Adjustment in Organic Thin-film Transistors Through the Use of Interface Amino Acids Interlayers” Eloi Ros
-----	--

O-2	Noise Based Variability Approach for DC Statistical Analysis of Organic TFT Based Circuits Aristeidis Nikolaou, Jakob Leise, Jakob Pruefer, Ute Zschieschang, Hagen Klauk, Ghader Darbandy and Alexander Kloes
O-3	Subphthalocyanine-Diketopyrrolopyrrole conjugates for Non-Fullerene Acceptor-based Polymer Solar Cells with a High Open Circuit Voltage José Guadalupe Sánchez López, María João Álvaro Martins, Giulia Lavarda, Desiré Molina Alcaide, Tomás Torres, Josep Pallarès, Ángela Sastre Santos and Lluís F. Marsal
O-4	Study of the Degradation of PTB7-Th:PC70BM-based Solar Cells using TiO_x as Electron Transport Layers under Ambient Environment Alfonsina Abat Amelenan Torimtubun, José G. Sánchez, Josep Pallarès and Lluís F. Marsal
O-6	New Deposition Technique for Inverted Polymer Solar Cells Using ZnO-ETL Enas Moustafa, José Sanchez, Lluís Marsal and Josep Pallarés
O-7	Design and Simulation of Flexible Thin-Film Electrodes for Cell Culture Stimulation Juan J. Montero-Rodríguez, Karla Ramirez-Sanchez, Gerardo Valladares-Castrillo, Esteban D. Avendano-Soto and Ricardo Starbird-Perez
O-8	Effect of Thermal Annealing up to 200°C on SnO Thin Films Deposited at Room Temperature by Direct Current Magnetron Sputtering Samuel Martínez Arreola, Salvador Ivan Garduño Vertiz, Norberto Hernandez Como and Magali Estrada del Cueto

Modeling

M-6	Does the threshold voltage extraction method affect device variability?, Gabriel Espineira, Antonio Jesus García Loureiro and Natalia Seoane
M-7	Numerical Simulation of Wideband SiC N-N Heterostructure Diode Udayan Patankar
M-8	Analytical Method Based On A Trapezoidal Shape For Edgeless Gate Enclosed (EGE) MOSFET Width Over Length Calculation Boris Contreras, Jean-Michel Sallese and Gladys Ducoudray
M-9	SPICE Simulation of Radiation Induced Charges and Currents in Silicon Substrate Chiara Rossi and Jean-Michel Sallese

FRIDAY, 28TH FEBRUARY

	VENTO 3	VENTO 2	
8:30 – 9:00	Invited “R&D Opportunities in Photovoltaic Systems” Pritpal Singh, PhD	LASCAS – Digital Communications	
9:00 – 9:20	A-7		
9:20 – 9:40	A-8		
9:40 – 10:00	D-7		
10:00 – 10:30	Coffee Break		
10:30 – 11:30	Keynote: “Artificial Neural Networks for EMC Engineering” Dr. Christian Schuster Hamburg University of Technology		
11:30 – 13:00	LUNCH		
13:00 – 14:00	Keynote: “The Medicine of the Future You'll Take Only Once, and it is Bioelectronic” Dr. Wouter Serdjin Delft University of Technology		
14:00 – 14:20	O10	Invited “Graphene for Radio Frequency Electronics” Henri Happy	
14:20 – 14:30	Invited “Musculoskeletal Modeling as a Tool for Biomechanical Analysis” Manuel Cardona	A10	
14:30 – 14:40		O11	
14:40 – 14:50		O12	A11
14:50 – 15:00		IEEE Special Interest Group on Humanitarian Technologies (SIGHT) – Funding Opportunities	
15:00 – 15:10	IEEE Special Interest Group on Humanitarian Technologies (SIGHT) – Funding Opportunities		
15:10 – 15:30			
15:30 – 16:00	Coffee Break		
16:00 – 16:20	Invited “Scaling Down Channel Dimensions in Thin-Film Transistors: Challenges and Prospects” Ananth Dodabalapur	LASCAS – System Simulation and Test	

16:20 – 16:40	M-10	
16:40 – 17:00	M-11	
17:30 – 18:00	CLOSING CEREMONY	

Device Physics

A-5	Invited “R&D Opportunities in Photovoltaic Systems” Pritpal Singh, PhD
A-6	Direct Source-to-Drain Tunneling Current in Ultra-Short Channel DG MOSFETs by Wavelet Transform Kerim Yilmaz, Atieh Farokhnejad, Francisco Criado, Benjamín Iñíguez, François Lime and Alexander Klös
A-7	Influence of thermal annealing on MIM and MIS structures with Al₂O₃ and a-HIZO deposited at low temperature Isai Hernandez, Ivan Garduño and Norberto Hernandez
A-8	Analysis of Inkjet Printing Conditions for ZnO Nanoparticles Patterns Towards the Fabrication of Fully Printed Thin Film Devices Josue Fajardo, Salvador Ivan Garduño and Magali Estrada del Cueto
A-10	Using Current Pulses to Control the Intermediate Conductance States in Hafnium Oxide-Based RRAM Devices Hector Garcia, Oscar G. Ossorio, Salvador Dueñas and Helena Castán
A-11	Evolution of Electron Device Education and Research at Rochester Institute of Technology Robert Pearson and Ivan Puchades
A-12	Invited “Scaling Down Channel Dimensions in Thin-Film Transistors: Challenges and Prospects” Ananth Dodabalapur

Organic Devices

O-9	Invited “Musculoskeletal Modeling as a Tool for Biomechanical Analysis” Manuel Cardona
O-10	Impact of the Hafnium Oxide as Hole Blocking Layer on the Performance of Organic Solar Cells Magaly Ramírez Como, Victor S. Balderrama Vázquez, Magali Estrada de Cueto, Angel Sacramento Orduño, José G. Sánchez López and Lluís F. Marsal
O-11	Inverted Polymer Solar Cells Using V₂O₅/NiO as anode selective contact: Degradation Study Angel Sacramento, Victor Balderrama, Magaly Ramírez-Como, José G. Sánchez, Magali Estrada and Lluís F. Marsal
O-12	Assessing water content in polymers using capacitive sensors: Impact of the water distribution Rosane Moura Dos Santos, Catherine Dehollain Dehollain, Marco Mattavelli, Diego Barrettino and Jean-Michel Sallese

Modeling

M-10	Modeling a nanometer FD-SOI transistor with a basic all-region MOSFET model Mariana Siniscalchi, Nicolás Gammarano, Sylvain Bourdel, Carlos Galup-Montoro and Fernando Silveira
------	---

M-11	Modeling and simulation of MEMS test structures using finite element method for stress mapping in thin film coatings Parsoua Abedini Sohi, Irina Stateikina and Mojtaba Kahrizi
-------------	---

Posters/Flash Session*

(Wednesday 26th February 15:00 – 16:00)

P1	Voice command integrated with Electric wheelchair system design and electro stimulator for people with spinal cord injury. Luisa Amanda Navarrete Traña
P2	Proposal of facial recognition system for optimized access control using IoT Federico Machado, Héctor Carías and Pedro Alvarez
P3	Facial Recognition System Model of Automated Registration with Computer Vision Julio Bello Pavón and Byron Murillo Melendez
P4	Loyal Lighting Smart lighting system with IoT. Kenneth Lacayo Arauz, Oscar Cruz Mendoza and Julio Bello Pavón
P5	Development of virtual plant over embedded system. Luis Kelman Belloso Huezo and Denis Alfredo Altuve Santamaría
P7	Division algorithms - From Past to Present Chance to Improve Area Time and Complexity for Digital Applications Udayan Patankar and Miguel Flores
P8	RFID Data-logger prototype to primary traceability in Nicaragua Gerardo Huerta Robles and Eliezer Mendez Delgado
P9	Sistema acuapónico automatizado para cultivo familiar en comunidades de terreno vulnerable en Nicaragua Cristian Alberto Garcia Cruz and Lesly Mariela Escobar Garcia
P10	Intelligent vehicle parking counting system in shopping centers through an Arduino app powered by solar energy. Danny Luna
P11	UV Meter for Testing Quality of Water treated by a Solar Water Disinfection System Javier Urquizo, Christa Cook, Wesley Shugart-Schmidt, Viviana Villavicencio and Pritpal Singh
P12	Automation of an electric block making machine with select material for the rural community of Quilaca, Chinandega through a pulley system Alexis Orlando Solis Melendez
P13	Design of a low-cost ECG implemented at Pastor Jimenes health center in Jalapa Nueva Segovia, Nicaragua Pedro Caceres and Brandon Sandy
P14	Design of a voltage multiplier module for tangent tests of dielectric loss angle to be used at National University of Engineering. UNI-Nicaragua. Luis Chévez